



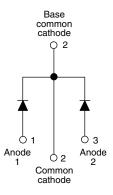
www.vishay.com

Vishay Semiconductors

HEXFRED® Ultrafast Soft Recovery Diode, 2 x 8 A



TO-247AC



| PRODUCT SUMMARY | | | | | |
|----------------------------------|------------|--|--|--|--|
| Package | TO-247AC | | | | |
| I _{F(AV)} | 2 x 8 A | | | | |
| V_{R} | 1200 V | | | | |
| V _F at I _F | 3.3 V | | | | |
| t _{rr} typ. | 28 ns | | | | |
| T _J max. | 150 °C | | | | |
| Diode variation | Single die | | | | |

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)





ROHS COMPLIANT HALOGEN FREE Available

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA16PA120C... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 8 A per leg continuous current, the VS-HFA16PA120C... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16PA120C... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|-----------------------------------|-------------------------|---------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Cathode to anode voltage | V_{R} | | 1200 | V | | |
| Maximum continuous forward current per leg | I_ | T _C = 100 °C | 8 | A | | |
| per device | - I _F | | 16 | | | |
| Single pulse forward current | I _{FSM} | | 130 | A | | |
| Maximum repetitive forward current | I _{FRM} | | 32 | | | |
| Maximum nawar dissination | 6 | T _C = 25 °C | 73.5 | W | | |
| Maximum power dissipation | P_{D} | T _C = 100 °C | 29 |] | | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | - 55 to + 150 | °C | | |



VS-HFA16PA120CPbF, VS-HFA16PA120C-N3

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| ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|----------------|--|------|------|-------|----|--|
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | | |
| Cathode to anode breakdown voltage | V_{BR} | Ι _R = 100 μΑ | 1200 | - | - | | |
| Maximum forward voltage | | I _F = 8.0 A | - | 2.6 | 3.3 | V | |
| | V_{FM} | I _F = 16 A | - | 3.4 | 4.3 | | |
| | | I _F = 8.0 A, T _J = 125 °C | - | 2.4 | 3.1 | | |
| Maximum reverse | | V _R = V _R rated | - | 0.31 | 10 | | |
| leakage current | | T _J = 125 °C, V _R = 0.8 x V _R rated | - | 135 | 1000 | μΑ | |
| Junction capacitance | C _T | V _R = 200 V | - | 11 | 20 | pF | |
| Series inductance | L _S | Measured lead to lead 5 mm from package | - | 8.0 | - | nH | |

| DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|---|---|--------------------------------------|--|------|------|-------|-------|--|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | | |
| | t _{rr} | $I_F = 1.0 \text{ A}, dI_F/dt = 200$ |) A/μs, V _R = 30 V | - | 28 | - | | |
| Reverse recovery time | t _{rr1} | T _J = 25 °C | | - | 63 | 95 | ns | |
| | t _{rr2} | T _J = 125 °C | I _F = 8.0 A dI _F /dt = 200 A/μs | - | 106 | 160 | | |
| Peak recovery current | I _{RRM1} | T _J = 25 °C | | - | 4.5 | 8.0 | Α | |
| | I _{RRM2} | T _J = 125 °C | | - | 6.2 | 11 | | |
| Dovorno rocoveni chargo | Q_{rr1} $T_J = 25 ^{\circ}C$ $V_{r-1} = 25 ^{\circ}C$ | $V_{\rm R} = 200 \text{ V}$ | - | 140 | 380 | nC | | |
| Reverse recovery charge | Q _{rr2} | T _J = 125 °C | -11 -22 - | - | 335 | 880 | IIC | |
| Peak rate of recovery current during t _b | dI _{(rec)M} /dt1 | T _J = 25 °C | | - | 133 | - | Δ/110 | |
| | dI _{(rec)M} /dt2 | T _J = 125 °C | | - | 85 | - | A/µs | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---|-------------------|--|--------------|------|------------|------------------------|--|
| PARAMETER | SYMBOL | BOL TEST CONDITIONS | | TYP. | MAX. | UNITS | |
| Lead temperature | T _{lead} | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | °C | |
| Thermal resistance, junction to case | R _{thJC} | | - | - | 1.7 | | |
| Thermal resistance, junction to ambient | R _{thJA} | R _{thJA} Typical socket mount | | - | 40 | K/W | |
| Thermal resistance, case to heatsink | R _{thCS} | R _{thCS} Mounting surface, flat, smooth and greased | | 0.25 | - | | |
| Weight | | | - | 6.0 | - | g | |
| vveignt | | | - | 0.21 | - | OZ. | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | |
| Marking device | | Case style TO-247AC (JEDEC) | HFA16PA120C | | | | |

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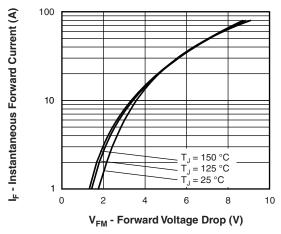


Fig. 1 - Maximum Forward Voltage Drop Characteristics

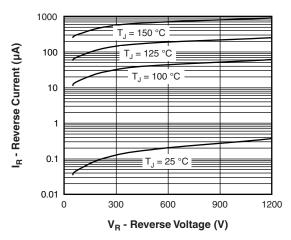


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

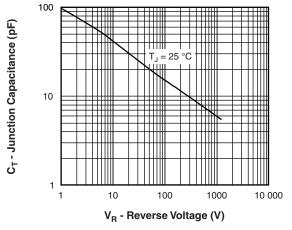


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

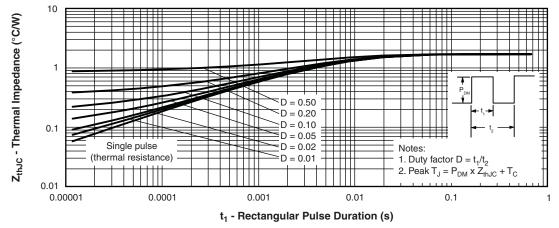


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



VS-HFA16PA120CPbF, VS-HFA16PA120C-N3

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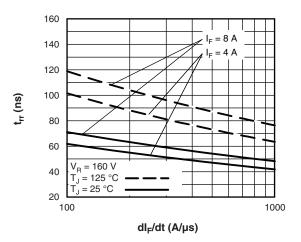


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

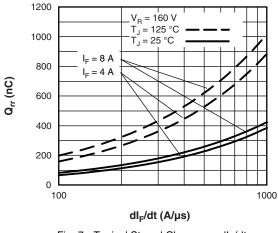


Fig. 7 - Typical Stored Charge vs. dl_F/dt

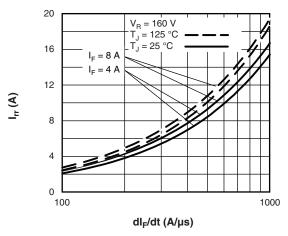


Fig. 6 - Typical Recovery Current vs. dI_F/dt

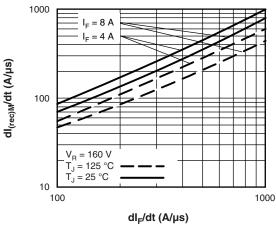


Fig. 8 - Typical $dl_{(rec)M}/dt$ vs. dl_F/dt

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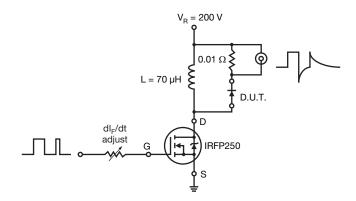
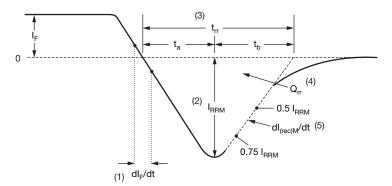


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RBM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

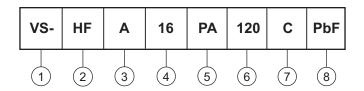
Fig. 10 - Reverse Recovery Waveform and Definitions

VS-HFA16PA120CPbF, VS-HFA16PA120C-N3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

- Electron irradiated

4 - Current rating (16 = 16 A)

5 - PA = TO-247AC

6 - Voltage rating: (120 = 1200 V)

7 - Circuit configuration

C = Common cathode

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

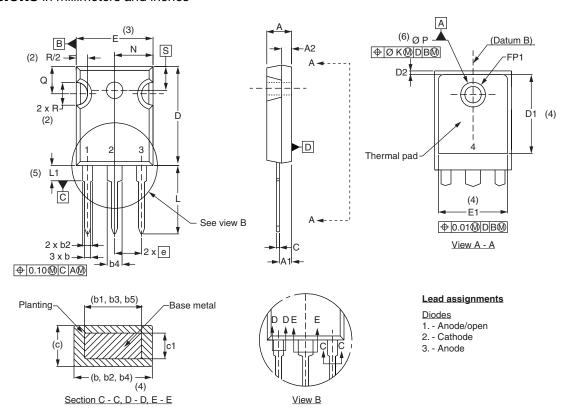
| ORDERING INFORMATION (Example) | | | | | | | |
|---|----|-----|-------------------------|--|--|--|--|
| PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | | |
| VS-HFA16PA120CPbF | 25 | 500 | Antistatic plastic tube | | | | |
| VS-HFA16PA120C-N3 | 25 | 500 | Antistatic plastic tube | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|--|-------------|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95223</u> | | | | | |
| Part marking information | TO-247ACPbF | www.vishay.com/doc?95226 | | | |
| | TO-247AC-N3 | www.vishay.com/doc?95007 | | | |



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DIMENSIONS in millimeters and inches



| SYMBOL MILLIMETERS | | INC | INCHES | | | |
|--------------------|-------|-------|--------|-------|-------|--|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 4.65 | 5.31 | 0.183 | 0.209 | | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | | |
| b3 | 1.65 | 2.37 | 0.065 | 0.094 | | |
| b4 | 2.59 | 3.43 | 0.102 | 0.135 | | |
| b5 | 2.59 | 3.38 | 0.102 | 0.133 | | |
| С | 0.38 | 0.86 | 0.015 | 0.034 | | |
| c1 | 0.38 | 0.76 | 0.015 | 0.030 | | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 | |
| D1 | 13.08 | - | 0.515 | - | 4 | |

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 0.51 | 1.30 | 0.020 | 0.051 | |
| E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| E1 | 13.72 | - | 0.540 | - | |
| е | 5.46 | BSC | 0.215 | BSC | |
| FK | 2. | 54 | 0.0 | 10 | |
| L | 14.20 | 16.10 | 0.559 | 0.634 | |
| L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| N | 7.62 | BSC | 0 | .3 | |
| ΦР | 3.56 | 3.66 | 0.14 | 0.144 | |
| ФР1 | - | 6.98 | - | 0.275 | |
| Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| R | 4.52 | 5.49 | 1.78 | 0.216 | |
| S | 5.51 | BSC | 0.217 | BSC | |

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



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